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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



Application Serial No. ....09/932,003  
 Filing Date .....August 17, 2001  
 Inventor ..... Cem Basceri  
 Assignee ..... Micron Technology, Inc.  
 Group Art Unit ..... 2813  
 Examiner ..... Y.B. Huynh  
 Attorney's Docket No. ....MI22-1731  
 Title: Methods of Forming Capacitor Constructions Comprising Perovskite-Type Dielectric Materials

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RESPONSE TO DECEMBER 4, 2002 OFFICE ACTION

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AMENDMENTSIn the Specification

Replace the Title with --Methods of Forming Capacitor Constructions Comprising  
 Perovskite-Type Dielectric Materials--.